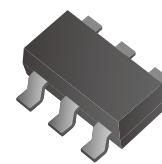


CPDT6-5V0USP-HF

RoHs Device

Halogen Free

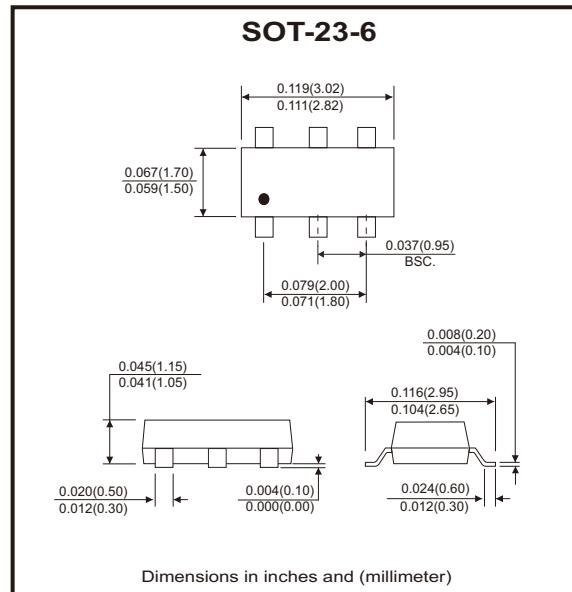


Features

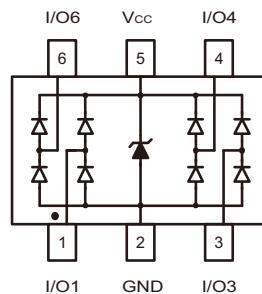
- Uni-directional ESD protection of four lines.
- IEC61000-4-2 Level 4 ESD protection.
- JESD22-A114-B ESD Rating of class 3B per human body model.
- Low reverse stand-off voltage: 5V
- Low reverse clamping voltage.
- Low leakage current.
- Fast response time.

Mechanical data

- Case: SOT-23-6 standard package molded plastic.
- Terminals: Solder plated, solderable per MIL-STD-750, method 2026.
- Mounting position: Any
- Weight: 0.015 grams(approx.).



Circuit Diagram



Maximum Ratings (at TA=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak pulse power	P _{PP} ⁽²⁾	125	W
Peak pulse current	I _{PP} ⁽²⁾	5	A
IEC 61000-4-2 voltage (I/O to GND & Vcc to GND)	Air model	±25	kV
	Contact model	±25	
	Per Human Body model	±16	
	Machine Model	±0.4	
Lead soldering temperature - Maximum(10 second duration)	T _L	260	°C
Junction temperature range	T _j	-55 to +150	°C
Storage temperature range	T _{STG}	-55 to +150	°C

Notes: 1. Device stressed with ten non-repetitive ESD pulses, Per channel (I/O to GND).

2. Non-repetitive current pulse 8/20µs exponential decay waveform according to IEC 61000-4-5.

Electrical Characteristics (at TA=25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Reverse stand-Off voltage		$V_{RWM}^{(1)}$			5	V
Breakdown voltage	$I_T = 1\text{mA}$	$V_{(BR)}$	6.5		8.8	V
	$I_T = 1\text{mA}$ Vcc to GND		5.8		8.1	V
Reverse leakage current	$V_{RWM} = 5\text{V}$ (I/O to GND & Vcc to GND)	I_R			1	μA
Forward voltage	$I_F = 10\text{mA}$ (I/O to GND & Vcc to GND)	V_F	0.5		1.0	V
Clamping voltage	$I_{PP} = 1\text{A}$ (I/O to GND & Vcc to GND)	$V_C^{(2)}$			15	V
	$I_{PP} = 5\text{A}$ (I/O to GND & Vcc to GND)				25	
Junction capacitance	$V_R = 0\text{V}$, $f = 1\text{MHz}$	C_j			0.8	pF
	$V_R = 0\text{V}$, $f = 1\text{MHz}$, I/O to I/O				0.4	

Notes: 1. Other voltages available upon request.

2. Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC61000-4-5.

Low Capacitance SMD ESD Protection Diode

Comchip
SMD Diode Specialist

Rating and Characteristic Curves (CPDT6-5V0USP-HF)

Fig.1 - 8/20 μ s Peak Pulse Current
Wave Form Acc. IEC 61000-4-5

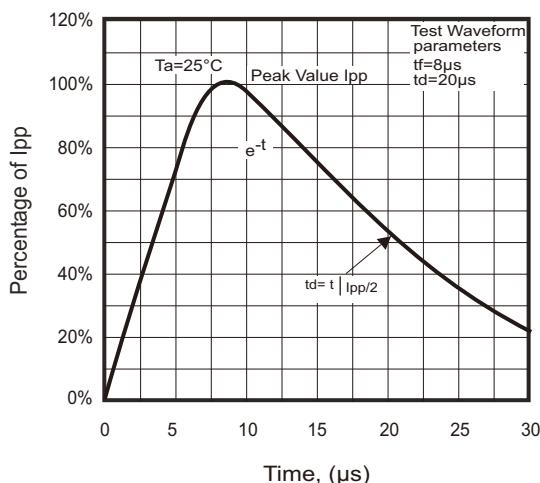


Fig.2 - Power Derating Curve

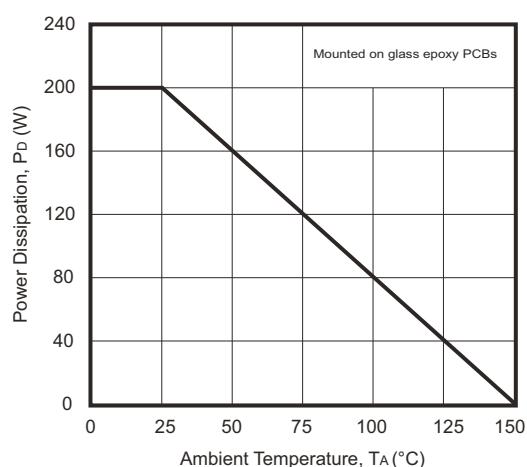


Fig.3 - Capacitance Characteristics

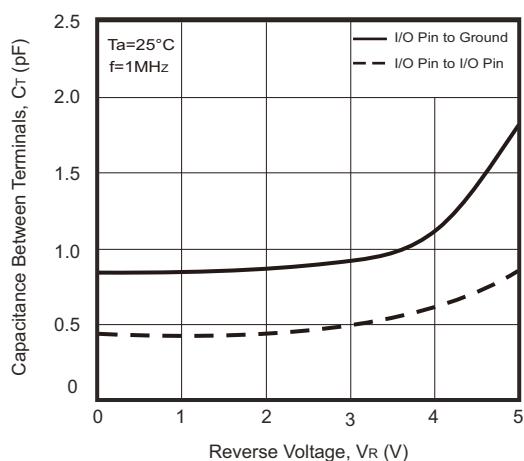
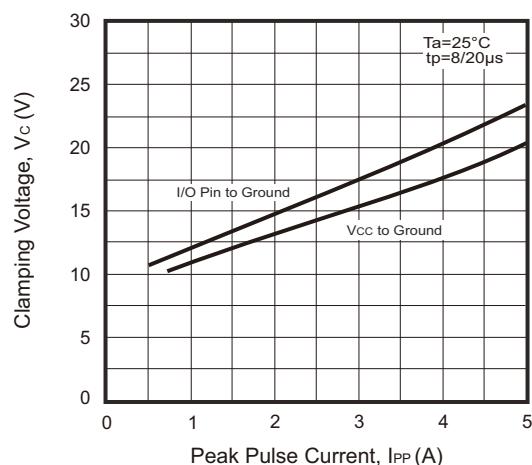
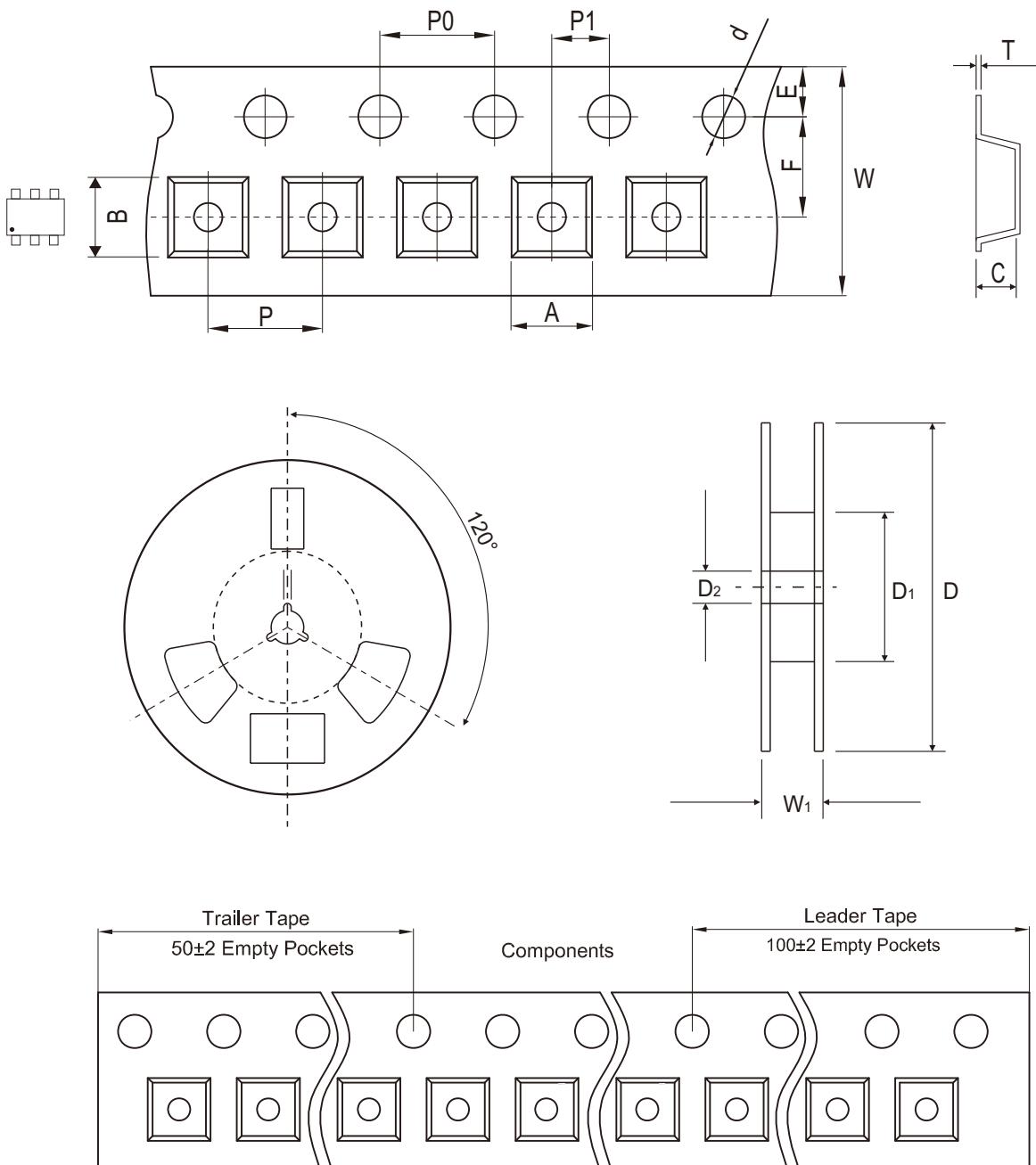


Fig.4 - Clamping Voltage Vs.
Peak Pulse Current



Reel Taping Specification



SOT-23-6	SYMBOL	A	B	C	d	D	D1	D2
	(mm)	3.17 ± 0.10	3.23 ± 0.10	1.37 ± 0.10	1.50 ± 0.05	$180.0 + 0.00 / - 0.30$	60.00 ± 0.50	13.00 ± 0.20
	(inch)	0.125 ± 0.004	0.127 ± 0.004	0.054 ± 0.004	0.059 ± 0.002	$7.087 + 0.00 / - 0.012$	2.362 ± 0.020	0.512 ± 0.008

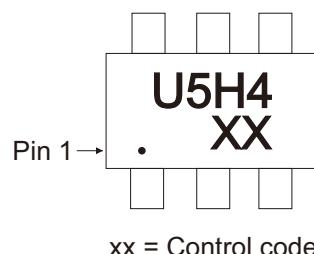
SOT-23-6	SYMBOL	E	F	P	P0	P1	W	W1
	(mm)	1.75 ± 0.10	3.50 ± 0.05	4.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.05	$8.00 + 0.30 / - 0.10$	12.30 ± 0.20
	(inch)	0.069 ± 0.004	0.138 ± 0.002	0.157 ± 0.004	0.157 ± 0.004	0.079 ± 0.002	$0.315 + 0.012 / - 0.004$	0.484 ± 0.008

Company reserves the right to improve product design , functions and reliability without notice.

REV:B

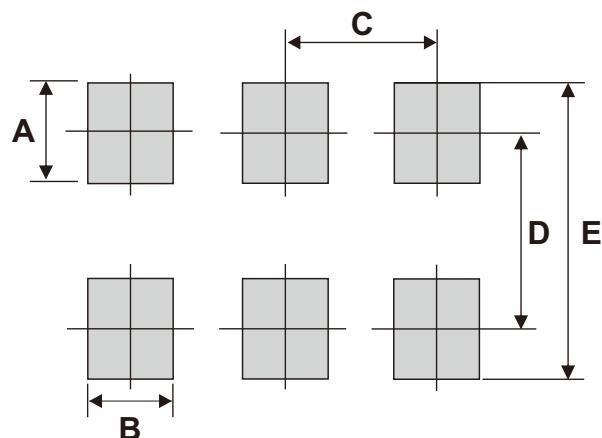
Marking Code

Part Number	Marking Code
CPDT6-5V0USP-HF	U5H4



Suggested P.C.B. PAD Layout

SIZE	SOT-23-6	
	(mm)	(inch)
A	1.00	0.039
B	0.70	0.028
C	0.95	0.037
D	2.40	0.094
E	3.40	0.134



Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
SOT-23-6	3,000	7